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CMOS Logic

■ GENERAL DESCRIPTION

The XC74UL14AA is a CMOS schmitt trigger inverter, manufactured using silicon gate CMOS fabrication.

CMOS low power circuit operation makes high speed LS-TTL operation achievable.

With a wave forming buffer connected internally, stabilized output can be achieved as the circuit offers high noise immunity.

As the XC74UL14AA is integrated into mini molded, SSOT-25 and SON-6 package, high density mounting is possible.

■ APPLICATIONS

- Palmtops
- Digital equipment

■ FEATURES

High Speed Operation : tpd = 2.3ns (TYP.)

Operating Voltage Range : 2V ~ 5.5V

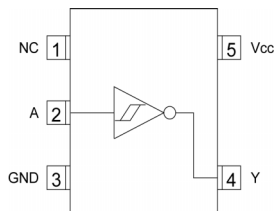
Low Power Consumption : 1 μ A (MAX.)

CMOS Schmitt Trigger Inverter

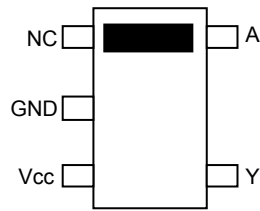
Ultra Small Packages : SSOT-25, SON-6*

* Under Development

■ PIN CONFIGURATION



SSOT-25
(TOP VIEW)
XC74UL14AAN



SON-6
(TOP VIEW)
XC74UL14AAR

■ FUNCTIONS

INPUT	OUTPUT
A	Y
H	L
L	H

H=High level

L=Low level

■ ABSOLUTE MAXIMUM RATINGS

Ta=-40°C~85°C

PARAMETER	SYMBOL	RATINGS	UNITS
Supply Voltage	VCC	-0.5~+6.0	V
Input Voltage	VIN	-0.5~+6.0	V
Output Voltage	VOUT	-0.5~VCC+0.5	V
Input Diode Current	I _{IK}	-20	mA
Output Diode Current	I _{OK}	±20	mA
Output Current	I _{OUT}	±25	mA
VCC,GND Current	I _{CC} ,I _{GND}	±50	mA
Power Dissipation	SSOT-25* ¹	150	mW
	SON-6* ²	200	
Storage Temperature Range	T _{stg}	-65~+150	°C

Voltage is all ground standardized.

* 1) Ta=55°C

* 2) Ta=25°C

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	V _{CC} (V)	CONDITIONS	UNITS
Supply Voltage	V _{CC}	—	2~5.5	V
Input Voltage	V _{IN}	—	0~5.5	V
Output Voltage	V _{OUT}	—	0~V _{CC}	V
Operating Temperature Range	Topr	—	-40~+85	°C
Output Current	I _{OH}	3.0	-4	mA
		4.5	-8	
	I _{OL}	3.0	4	
		4.5	8	

DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	V _{CC} (V)	CONDITIONS	Ta=25°C			Ta=-40°C~85°C		UNITS	
				MIN.	TYP.	MAX.	MIN.	MAX.		
Threshold Voltage	V _{T+}	2.0		—	—	2.2	—	2.2	V	
		3.0		—	—	3.15	—	3.15		
		5.5		—	—	3.85	—	3.85		
	V _{T-}	2.0		0.9	—	—	0.9	—	V	
		3.0		1.35	—	—	1.35	—		
		5.5		1.65	—	—	1.65	—		
Hysteresis Voltage	V _H	3.0	0.25	—	1.2	0.25	1.2			
		4.5	0.30	—	1.4	0.30	1.4			
		5.5	0.35	—	1.6	0.35	1.6			
Output Voltage	V _{OH}	2.0	V _{IN} =V _{IL}	I _{OH} =-50 μA	1.9	2.0	—	1.9	—	V
		3.0			2.9	3.0	—	2.9	—	
		4.5			4.4	4.5	—	4.4	—	
		3.0			2.58	—	—	2.48	—	
		4.5			3.94	—	—	3.80	—	
	V _{OL}	V _{IN} =V _{IH}	I _{OL} =50 μA	2.0	—	—	0.1	—	0.1	V
				3.0	—	—	0.1	—	0.1	
				4.5	—	—	0.1	—	0.1	
				3.0	—	—	0.36	—	0.44	
				4.5	—	—	0.36	—	0.44	
Input Current	I _{IN}	5.5	V _{IN} =V _{CC} or GND	-0.1	—	0.1	-1.0	1.0	μA	
Static Supply Current	I _{CC}	5.5	V _{IN} =V _{CC} or GND, I _{OUT} =0 μA	—	—	1.0	—	10.0		

SWITCHING ELECTRICAL CHARACTERISTICS

tr=tf=3ns

PARAMETER	SYMBOL	C _L	V _{CC} (V)	CONDITIONS	Ta=25°C			Ta=-40°C~85°C		UNITS
					MIN.	TYP.	MAX.	MIN.	MAX.	
Delay Time	t _{PLH}	15pF	3.3		—	2.8	12.8	1.0	15.0	ns
			5.0		—	2.1	8.6	1.0	10.0	
		50pF	3.3		—	4.3	16.3	1.0	18.5	ns
			5.0		—	3.1	10.6	1.0	12.0	
	t _{PHL}	15pF	3.3		—	3.1	12.8	1.0	15.0	ns
			5.0		—	2.5	8.6	1.0	10.0	
		50pF	3.3		—	4.4	16.3	1.0	18.5	ns
			5.0		—	3.4	10.6	1.0	12.0	
Input Capacitance	C _{IN}	—	5.0	V _{IN} =V _{CC} or GND	—	2	10	—	10	pF
Power Dissipation Capacitance	C _{pd}	No Load, f=1MHz			—	10	—	—	—	pF

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